Product data sheet

1. General description

Silicon Carbide Schottky diode in a IITO220-2L plastic package, designed for high frequency switched-mode power supplies.



2. Features and benefits

- · Highly stable switching performance
- · Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- · Reduced cooling requirements
- RoHS compliant

3. Applications

- Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes	S Values			Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage				650		V
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 124 °C; Fig. 1; Fig. 2; Fig. 3		4		А	
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static characteristics							
V_{F}	forward voltage	I _F = 4 A; T _j = 25 °C; <u>Fig. 5</u>		-	1.45	1.70	V
		I _F = 4 A; T _j = 150 °C; <u>Fig. 5</u>		-	1.80	2.20	V

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	<u> </u>	× 14 A
2	Α	anode		K -
mb	n.c.	mounting base; isolated		
			89	
			<u> </u>	
			1 2	

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WNSC5D04650Y	IITO220-2L	WNSC5D04650Y6Q	Tube	50	IITO220P-2L	13-Mar-2023

7. Marking

Table 4. Marking codes

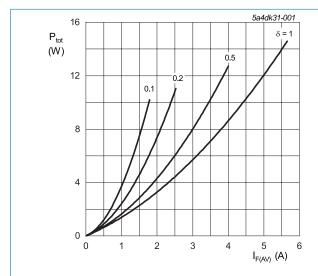
Type number	Marking codes
WNSC5D04650Y	WNSC5D 04650Y

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			650	V
V_{RWM}	crest working reverse voltage			650	V
V_R	reverse voltage	DC		650	V
$I_{F(AV)}$	average forward current	δ = 0.5; square-wave pulse; $T_{mb} \le 124$ °C; Fig. 1; Fig. 2; Fig. 3		4	А
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 μs; T _{mb} ≤ 124 °C; square-wave pulse		8	А
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		26	Α
		t _p = 10 μs; T _{j(init)} = 25 °C; square-wave pulse		280	Α
l ² t	I ² t for fusing	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		3.38	A ² s
T _{stg}	storage temperature			-55 to 175	°C
T _j	junction temperature			-55 to 175	°C



$$\begin{split} I_{F(AV)} &= I_{F(RMS)} \times \sqrt{\delta} \\ V_o &= 1.131 \text{ V; } R_s = 0.2558 \text{ } \Omega \end{split}$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

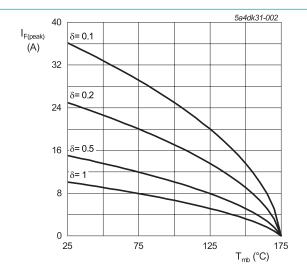
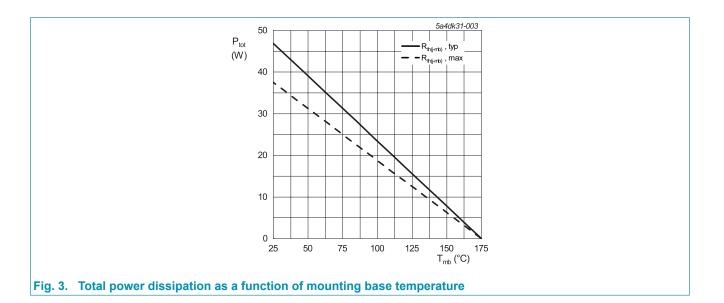


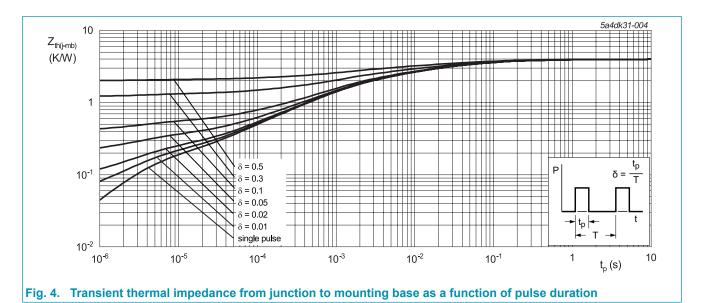
Fig. 2. Current derating as a function of mounting base temperature



9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 4		-	3.2	4	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air		-	60	-	K/W



10. Isolation characteristics

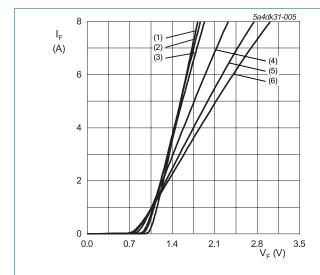
Table 7. Isolation characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$V_{\text{isol}(\text{RMS})}$	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; T _h = 25 °C; RH \leq 65 %		-	-	2500	V

11. Characteristics

Table 8. Characteristics

	Deremeter	Conditions	Notes	Min	Turn	Mov	I I Incid
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	racteristics						
V_{F}	forward voltage	I _F = 4 A; T _j = 25 °C; <u>Fig. 5</u>		-	1.45	1.70	V
		I _F = 4 A; T _j = 150 °C; <u>Fig. 5</u>		-	1.80	2.20	V
		I _F = 4 A; T _j = 175 °C; <u>Fig. 5</u>		-	2.00	2.30	V
I _R	reverse current	V _R = 650 V; T _j = 25 °C; <u>Fig. 6</u>		-	0.2	20	μA
		V _R = 650 V; T _j = 175 °C; <u>Fig. 6</u>		-	10	100	μA
Dynamic	characteristics				'		
Q_r	recovered charge	$I_F = 4 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 25 ^{\circ}\text{C}; \frac{\text{Fig. 7}}{2}$		-	6	-	nC
C _d	diode capacitance	f = 1 MHz; V _R = 1 V; T _j = 25 °C		-	138	-	pF
		f = 1 MHz; V _R = 300 V; T _j = 25 °C		-	17	-	pF
		f = 1 MHz; V _R = 600 V; T _j = 25 °C		-	15	-	pF
E _{as}	non-repetitive avalanche energy	I _R = 2.8 A; T _{j(init)} = 25 °C; L = 5 mH		20	-	-	mJ



 $V_0 = 1.131 \text{ V}; R_s = 0.2558 \Omega$

(1) T_i = -55 °C; typical values

(2) T_i = 0 °C; typical values

(3) T_i = 25 °C; typical values

(4) T_j = 100 °C; typical values (5) T_j = 150 °C; typical values (6) T_j = 175 °C; typical values

Fig. 5. Forward current as a function of forward

voltage; typical values

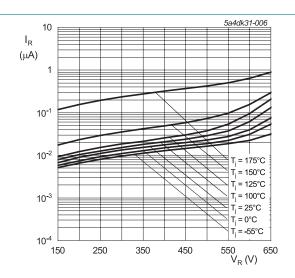
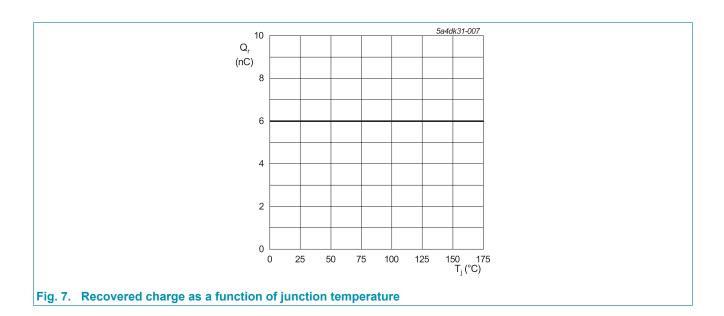
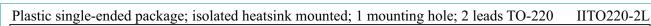
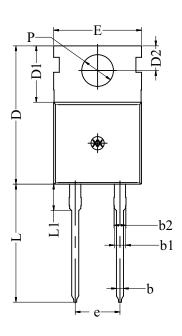


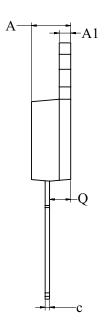
Fig. 6. Reverse leakage current as a function of reverse voltage; typical value

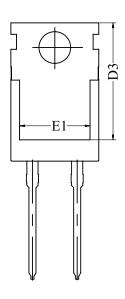


12. Package outline









Dim	All Dir	nensions in M	Illimeters
Dilli	Min	Тур	Max
A	4.30	4.45	4.70
A1	1.25	1.30	1.40
ь	0.60	0.80	0.90
b1	1.10	1.27	1.40
b2	1.32	1.37	1.72
c	0.40	0.50	0.60
D	15.20	15.70	16.00
D1	6.20	6.40	6.60
D2	2.70	2.80	3.00
D3	12.98	13.28	13.58
E	9.70	10.00	10.30
E1	7.50	8.00	8.50
e		5.08(BSC)	
L	12.80	13.40	14.00
L1	2.80	3.00	3.20
P	3.50	3.60	3.70
Q	2.20	2.40	2.60

13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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